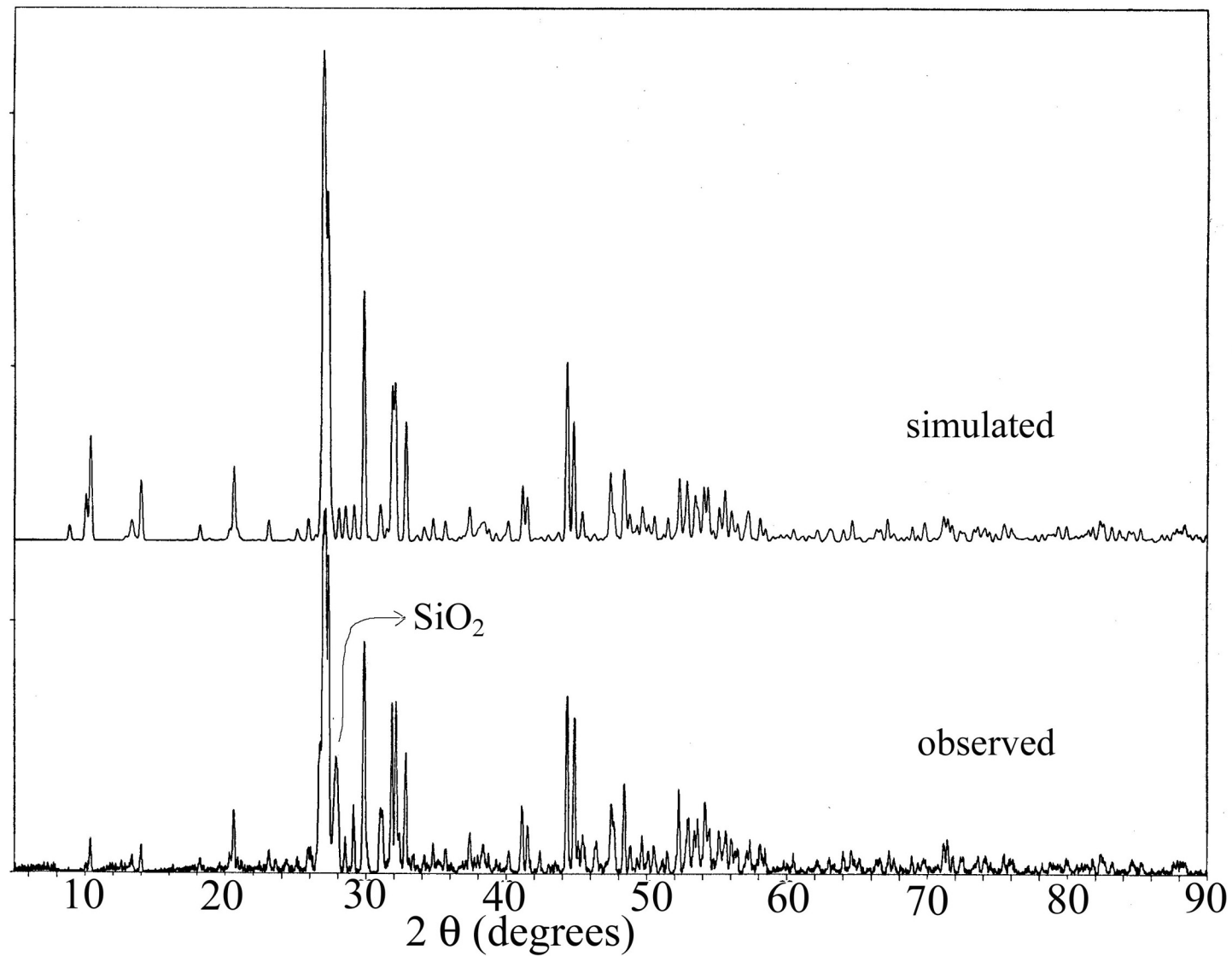


I
n
t
e
n
s
i
t
y



simulated

observed

SiO_2

10

20

2θ (degrees)

40

50

60

70

80

90